





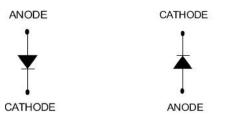
# 245NQ015/R-1 SCHOTTKY RECTIFIER



### **Features**

- 125°C T<sub>J</sub> operation(V<sub>R</sub><5V)</li>
- Unique high power, Half-Pak module
- Optimized for OR-ing applications
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



245NQ015-1 245NQ015R-1

### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	_	15(DC) 25(Working)	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =70°C, rectangular wave form	240	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	3600	Α
Non-Repetitive Avalanche Energy	Eas	T <sub>J</sub> =25℃,I <sub>AS</sub> =2A,L=4.5mH	9	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	Current decaying linearly to zero in 1 µsec Frequency limited by $T_J$ max. $V_A$ =3 $\times$ V $_R$ typical	2	А

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# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V	@ 240A, Pulse, T <sub>J</sub> = 25 °C	0.37	0.40	V
	V <sub>F1</sub>	@ 480A, Pulse, T <sub>J</sub> = 25 °C	-	0.51	V
	V <sub>F2</sub>	@ 240A, Pulse, T <sub>J</sub> = 125 °C	0.32	0.34	V
	V F2	@ 480A, Pulse, T <sub>J</sub> = 125 °C	-	0.44	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	20	80	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R T_J = 100  ^{\circ}\text{C}$	2000	4000	mA
	I <sub>R3</sub>	@V <sub>R</sub> = 12V, T <sub>J</sub> = 100 °C	1800	3560	mA
	$I_{R4}$	@V <sub>R</sub> = 5V, T <sub>J</sub> = 100 °C	1000	2160	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	13200	15800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +125		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to	+150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	0.2	:0	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	T <sub>M</sub>	Non-lubricated threads	Mounting Torque	23(min) 29(max)	- Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	25.6		g
Case Style	PRM1-1				

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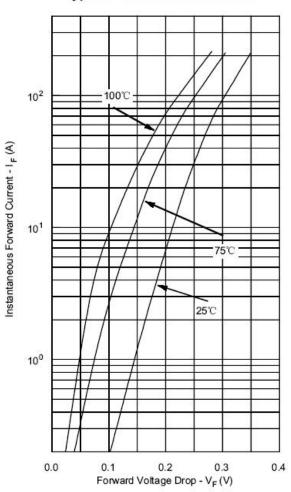




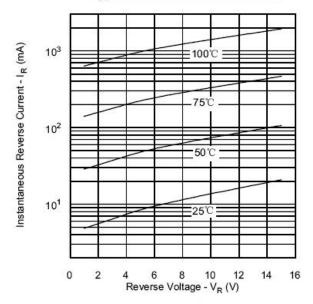


### **Ratings and Characteristics Curves**

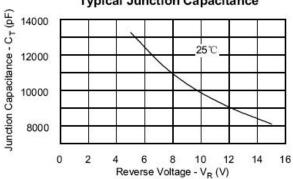
#### **Typical Forward Characteristics**



#### Typical Reverse Characteristics



#### Typical Junction Capacitance

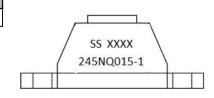


# **Ordering Information**

Device	Package	Shipping	
245NQ015-1	PRM1-1(Pb-Free)	27pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



Where XXXX is YYWW

1st row SS YYWW 2nd row 245NQ015-1 SS = SS = Year = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

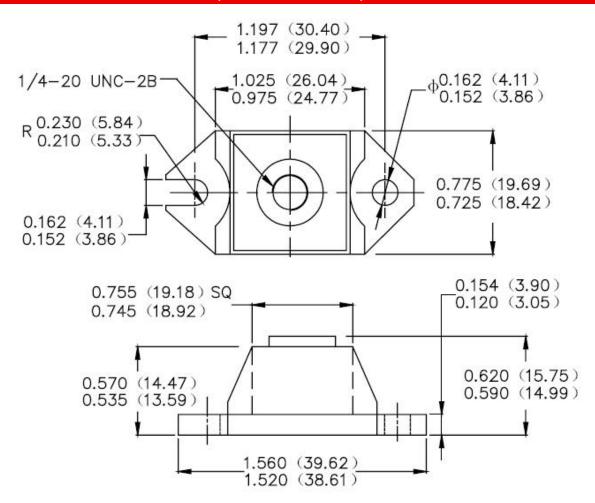
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# **Mechanical Dimensions PRM1-1 (Inches/Millimeters)**



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